



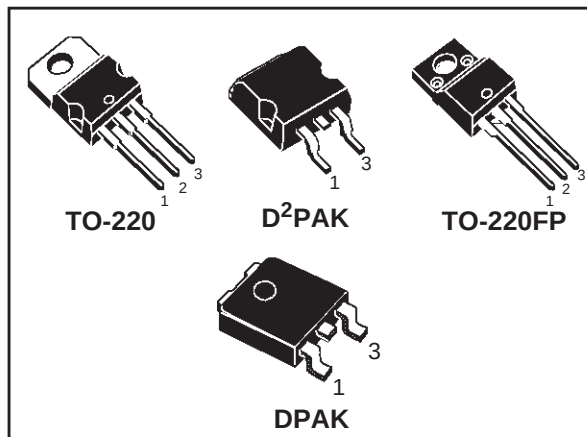
# STGP7NB60K - STGP7NB60KFP STGB7NB60K - STGD7NB60K

N-CHANNEL 7A - 600V - TO-220/FP/D<sup>2</sup>PAK/DPAK

PowerMESH™ IGBT

| TYPE         | V <sub>CES</sub> | V <sub>CE(sat)</sub><br>(Typ) @125°C | I <sub>C</sub><br>@125°C |
|--------------|------------------|--------------------------------------|--------------------------|
| STGP7NB60K   | 600 V            | < 1.9 V                              | 7 A                      |
| STGP7NB60KFP | 600 V            | < 1.9 V                              | 7 A                      |
| STGB7NB60K   | 600 V            | < 1.9 V                              | 7 A                      |
| STGD7NB60K   | 600 V            | < 1.9 V                              | 7 A                      |

- HIGH INPUT IMPEDANCE (VOLTAGE DRIVEN)
- LOW ON-VOLTAGE DROP (V<sub>cesat</sub>)
- LOW GATE CHARGE
- HIGH CURRENT CAPABILITY
- OFF LOSSES INCLUDE TAIL CURRENT
- VERY HIGH FREQUENCY OPERATION
- SHORT CIRCUIT RATED



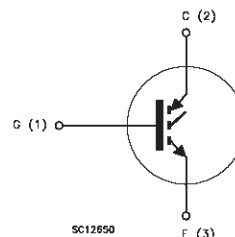
## DESCRIPTION

Using the latest high voltage technology based on a patented strip layout, STMicroelectronics has designed an advanced family of IGBTs, the PowerMESH™ IGBTs, with outstanding performances. The suffix "K" identifies a family optimized for high frequency motor control applications with short circuit withstand capability.

## APPLICATIONS

- HIGH FREQUENCY MOTOR CONTROLS
- SMPS AND PFC IN BOTH HARD SWITCH AND RESONANT TOPOLOGIES

## INTERNAL SCHEMATIC DIAGRAM



## ORDERING INFORMATION

| SALES TYPE   | MARKING    | PACKAGE            | PACKAGING   |
|--------------|------------|--------------------|-------------|
| STGP7NB60K   | GP7NB60K   | TO-220             | TUBE        |
| STGP7NB60KFP | GP7NB60KFP | TO-220FP           | TUBE        |
| STGB7NB60KT4 | GB7NB60K   | D <sup>2</sup> PAK | TAPE & REEL |
| STGD7NB60KT4 | GD7NB60K   | DPAK               | TAPE & REEL |

## STGP7NB60K/FP/STGB7NB60K/STGD7NB60K

### ABSOLUTE MAXIMUM RATINGS

| Symbol                         | Parameter                                                | Value                       |          |      | Unit |
|--------------------------------|----------------------------------------------------------|-----------------------------|----------|------|------|
|                                |                                                          | TO-220 / D <sup>2</sup> PAK | TO-220FP | DPAK |      |
| V <sub>CES</sub>               | Collector-Emitter Voltage (V <sub>GS</sub> = 0)          | 600                         |          |      | V    |
| V <sub>ECR</sub>               | Emitter-Collector Voltage                                | 20                          |          |      | V    |
| V <sub>GE</sub>                | Gate-Emitter Voltage                                     | ±20                         |          |      | V    |
| I <sub>C</sub>                 | Collector Current (continuous) at T <sub>C</sub> = 25°C  | 14                          |          |      | A    |
| I <sub>C</sub>                 | Collector Current (continuous) at T <sub>C</sub> = 100°C | 7                           |          |      | A    |
| I <sub>CM</sub> <sup>(n)</sup> | Collector Current (pulsed)                               | 50                          |          |      | A    |
| P <sub>TOT</sub>               | Total Dissipation at T <sub>C</sub> = 25°C               | 65                          | 28       | 45   | W    |
|                                | Derating Factor                                          | 0.64                        | 0.28     | 0.64 | W/°C |
| V <sub>ISO</sub> (1)           | Insulation Withstand Voltage A.C.                        | --                          | 2500     | --   | V    |
| T <sub>stg</sub>               | Storage Temperature                                      | -65 to 150                  |          |      | °C   |
| T <sub>j</sub>                 | Max. Operating Junction Temperature                      | 150                         |          |      | °C   |

(n) Pulse width limited by safe operating area

(1) (t = 1 sec; T<sub>C</sub> = 25°C)

### THERMAL DATA

|                       |                                         | TO-220 | D <sup>2</sup> PAK | TO-220FP | DPAK |      |
|-----------------------|-----------------------------------------|--------|--------------------|----------|------|------|
| R <sub>thj-case</sub> | Thermal Resistance Junction-case Max    | 1.62   |                    | 4.1      | 2.1  | °C/W |
| R <sub>thj-amb</sub>  | Thermal Resistance Junction-ambient Max | 62.5   |                    |          | 100  | °C/W |
| R <sub>thc-h</sub>    | Thermal Resistance Case-heatsink Typ    | 0.5    |                    |          |      | °C/W |

### ELECTRICAL CHARACTERISTICS (T<sub>CASE</sub> = 25 °C UNLESS OTHERWISE SPECIFIED)

#### MAIN PARAMETERS

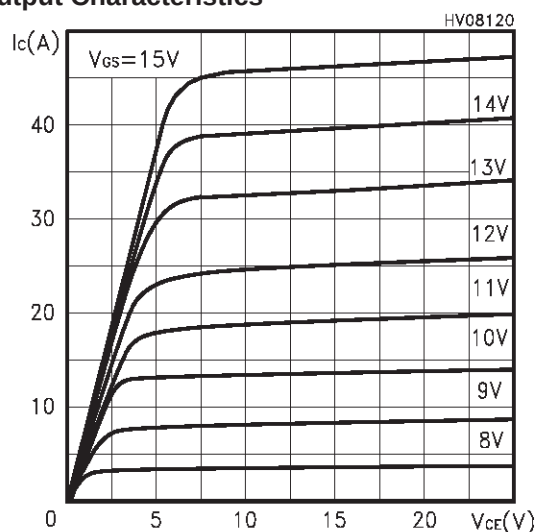
| Symbol                | Parameter                                          | Test Conditions                                                                                                    | Min. | Typ.       | Max.      | Unit     |
|-----------------------|----------------------------------------------------|--------------------------------------------------------------------------------------------------------------------|------|------------|-----------|----------|
| V <sub>BR</sub> (CES) | Collector-Emitter Breakdown Voltage                | I <sub>C</sub> = 250 μA, V <sub>GE</sub> = 0                                                                       | 600  |            |           | V        |
| I <sub>CES</sub>      | Collector cut-off (V <sub>GE</sub> = 0)            | V <sub>CE</sub> = Max Rating, T <sub>C</sub> = 25 °C<br>V <sub>CE</sub> = Max Rating, T <sub>C</sub> = 125 °C      |      |            | 50<br>500 | μA<br>μA |
| I <sub>GES</sub>      | Gate-Emitter Leakage Current (V <sub>CE</sub> = 0) | V <sub>GE</sub> = ±20V, V <sub>CE</sub> = 0                                                                        |      |            | ±100      | nA       |
| V <sub>GE(th)</sub>   | Gate Threshold Voltage                             | V <sub>CE</sub> = V <sub>GE</sub> , I <sub>C</sub> = 250μA                                                         | 5    |            | 7         | V        |
| V <sub>CE(sat)</sub>  | Collector-Emitter Saturation Voltage               | V <sub>GE</sub> = 15V, I <sub>C</sub> = 7 A<br>V <sub>GE</sub> = 15V, I <sub>C</sub> = 7 A, T <sub>j</sub> = 125°C |      | 2.3<br>1.9 | 2.8       | V<br>V   |

## MAIN PARAMETERS

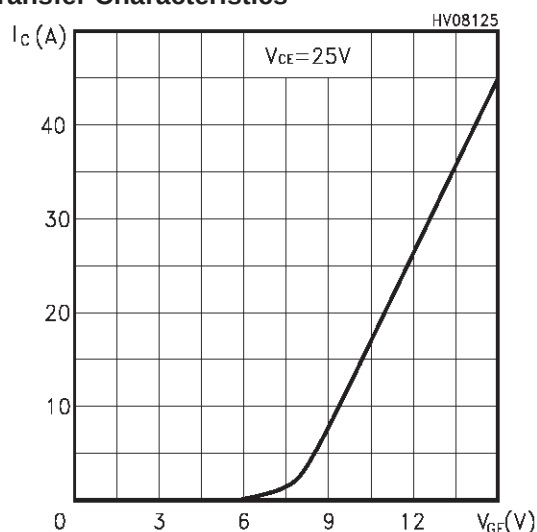
| Symbol                                                                        | Parameter                                                                                                              | Test Conditions                                                                             | Min. | Typ.                                  | Max. | Unit                                       |
|-------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------------|------|---------------------------------------|------|--------------------------------------------|
| $g_{fs}$                                                                      | Forward Transconductance                                                                                               | $V_{CE} = 15V, I_C = 7 A$                                                                   |      | 3.7                                   |      | S                                          |
| $C_{ies}$<br>$C_{oes}$<br>$C_{res}$                                           | Input Capacitance<br>Output Capacitance<br>Reverse Transfer Capacitance                                                | $V_{CE} = 25V, f = 1 MHz, V_{GE} = 0$                                                       |      | 495<br>77<br>13                       |      | pF<br>pF<br>pF                             |
| $Q_g$<br>$Q_{ge}$<br>$Q_{gc}$                                                 | Total Gate Charge<br>Gate-Emitter Charge<br>Gate-Collector Charge                                                      | $V_{CE} = 480V, I_C = 7 A,$<br>$V_{GE} = 15V$                                               |      | 32.7<br>5.9<br>18.3                   |      | nC<br>nC<br>nC                             |
| tscw                                                                          | Short Circuit Withstand Time                                                                                           | $V_{ce} = 0.5 V_{BR}(CES), V_{GE}=15V,$<br>$T_j = 125^{\circ}C, R_G = 10 \Omega$            | 10   |                                       |      | $\mu s$                                    |
| $t_{d(on)}$<br>$t_r$                                                          | Turn-on Delay Time<br>Rise Time                                                                                        | $V_{CC} = 480 V, I_C = 7 A$<br>$R_G = 10\Omega, V_{GE} = 15 V$                              |      | 15<br>6                               |      | ns<br>ns                                   |
| $t_c$<br>$t_r(V_{off})$<br>$t_{d(off)}$<br>$t_f$<br>$E_{off(**)}$<br>$E_{ts}$ | Cross-over Time<br>Off Voltage Rise Time<br>Delay Time<br>Fall Time<br>Turn-off Switching Loss<br>Total Switching Loss | $V_{CC} = 480 V, I_C = 7 A,$<br>$R_{GE} = 10 \Omega, V_{GE} = 15 V$                         |      | 85<br>20<br>75<br>70<br>85<br>235     |      | ns<br>ns<br>ns<br>ns<br>$\mu J$<br>$\mu J$ |
| $t_c$<br>$t_r(V_{off})$<br>$t_{d(off)}$<br>$t_f$<br>$E_{off(**)}$<br>$E_{ts}$ | Cross-over Time<br>Off Voltage Rise Time<br>Delay Time<br>Fall Time<br>Turn-off Switching Loss<br>Total Switching Loss | $V_{CC} = 480 V, I_C = 7 A,$<br>$R_{GE} = 10 \Omega, V_{GE} = 15 V$<br>$T_j = 125^{\circ}C$ |      | 150<br>50<br>110<br>110<br>220<br>405 |      | ns<br>ns<br>ns<br>ns<br>$\mu J$<br>$\mu J$ |

(\*\*) Losses include Also the Tail (Jedec Standardization)

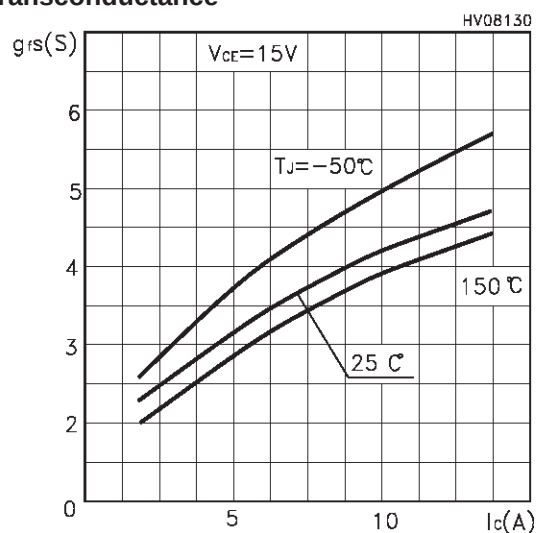
## Output Characteristics



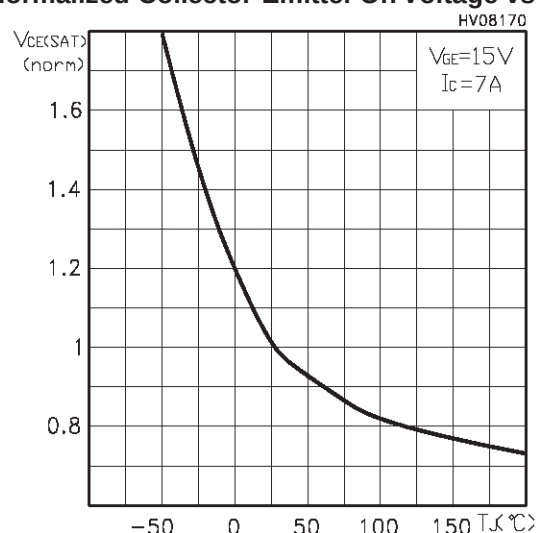
## Transfer Characteristics



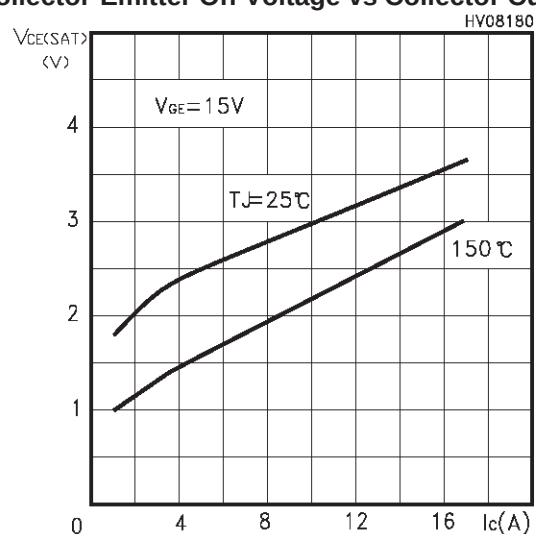
## Transconductance



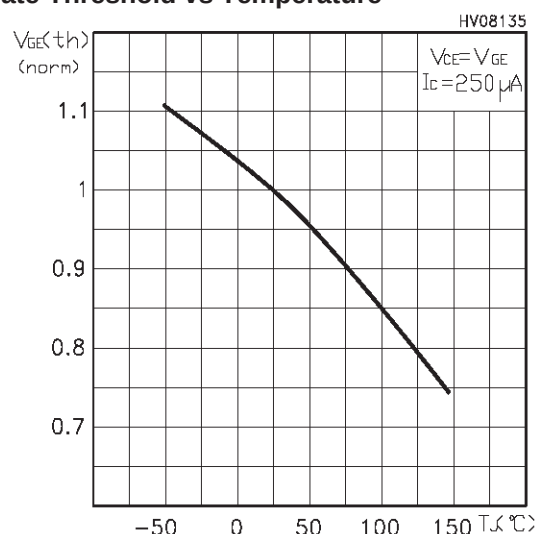
## Normalized Collector-Emitter On Voltage vs Temp.



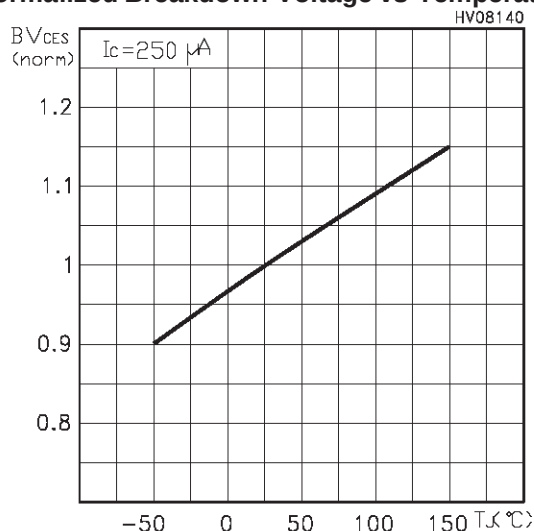
## Collector-Emitter On Voltage vs Collector Current



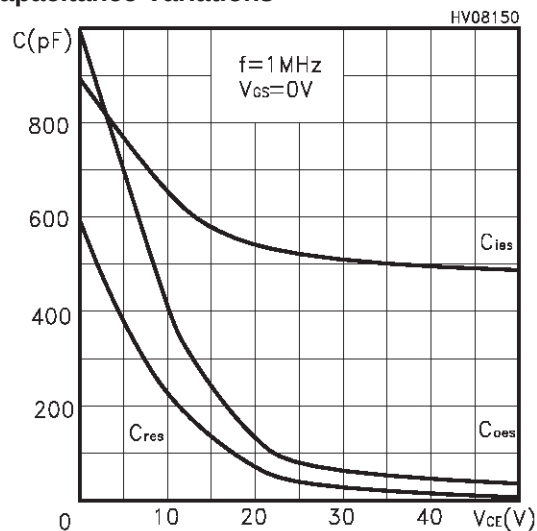
## Gate Threshold vs Temperature



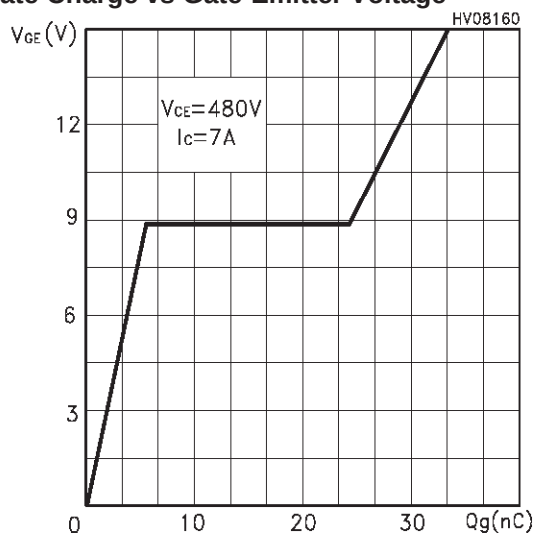
Normalized Breakdown Voltage vs Temperature



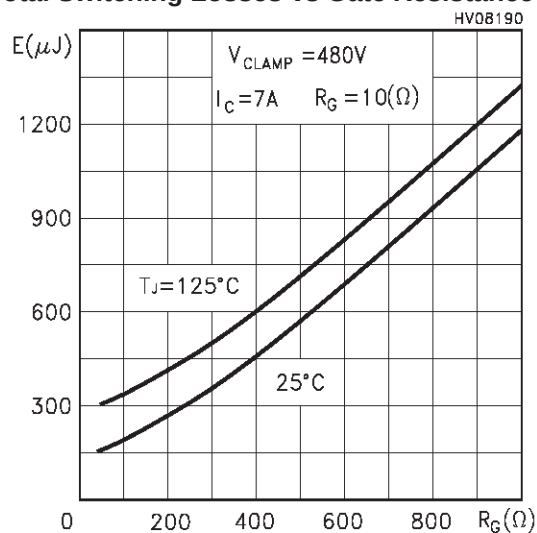
Capacitance Variations



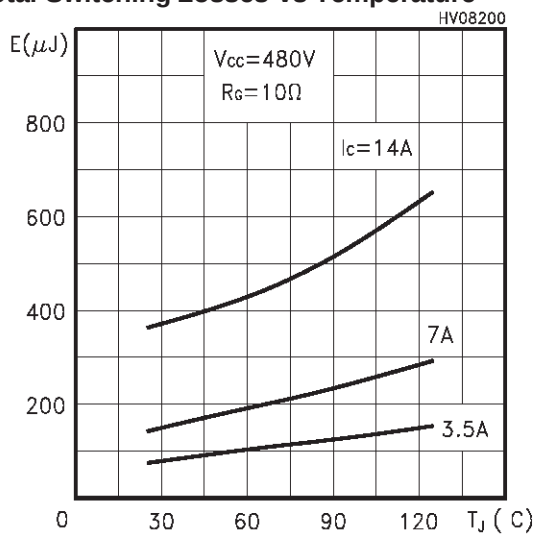
Gate Charge vs Gate-Emmitter Voltage



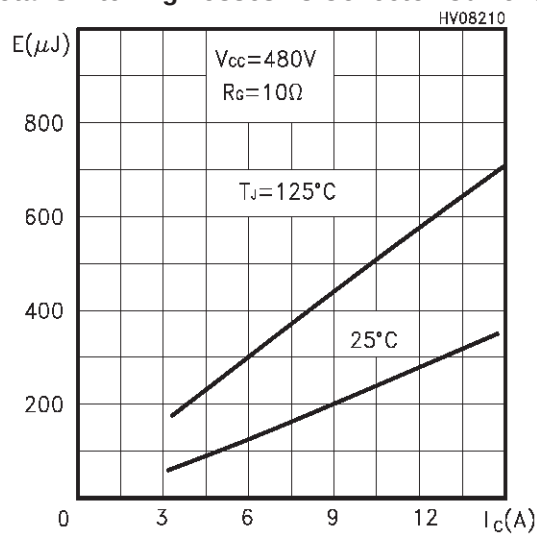
Total Switching Losses vs Gate Resistance



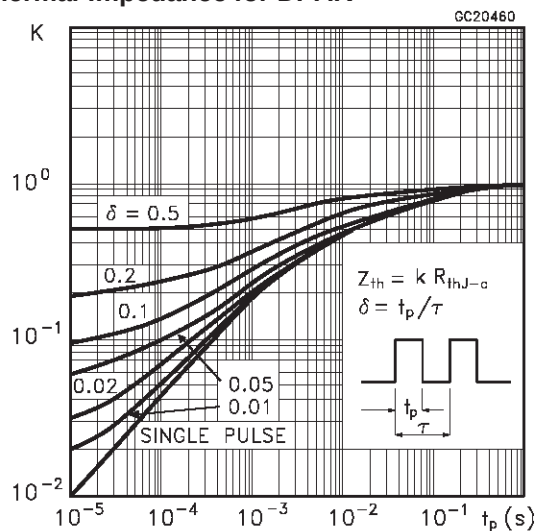
Total Switching Losses vs Temperature



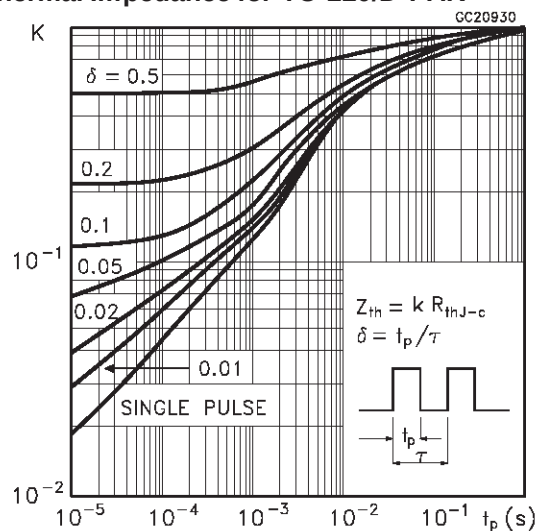
Total Switching Losses vs Collector Current



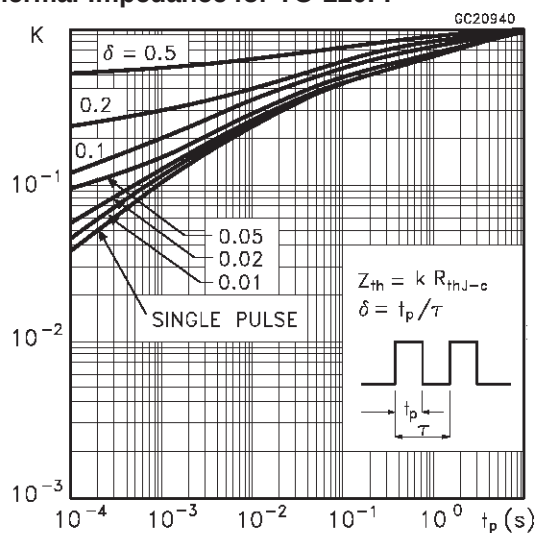
Thermal Impedance for DPAK



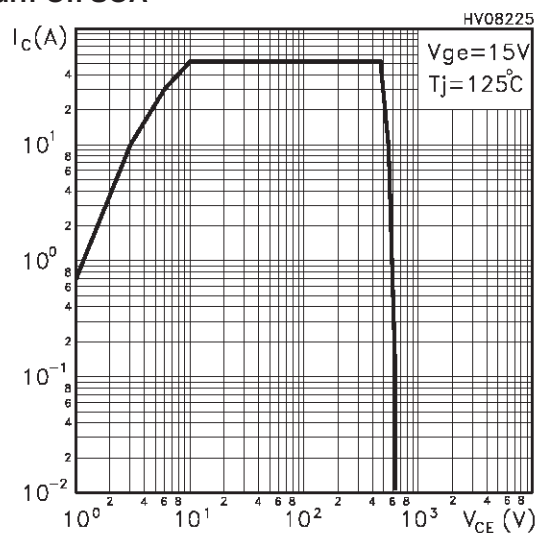
Thermal Impedance for TO-220/D<sup>2</sup>PAK



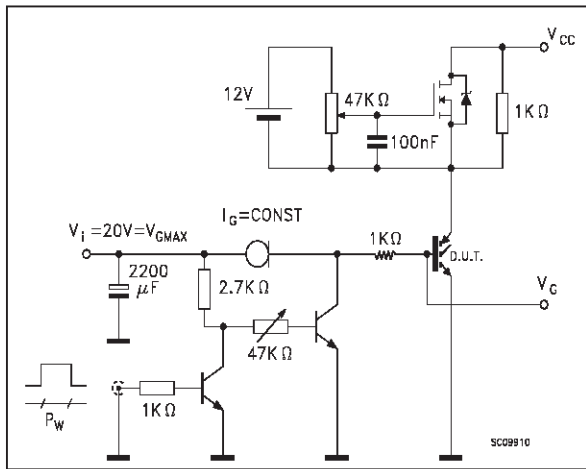
Thermal Impedance for TO-220FP



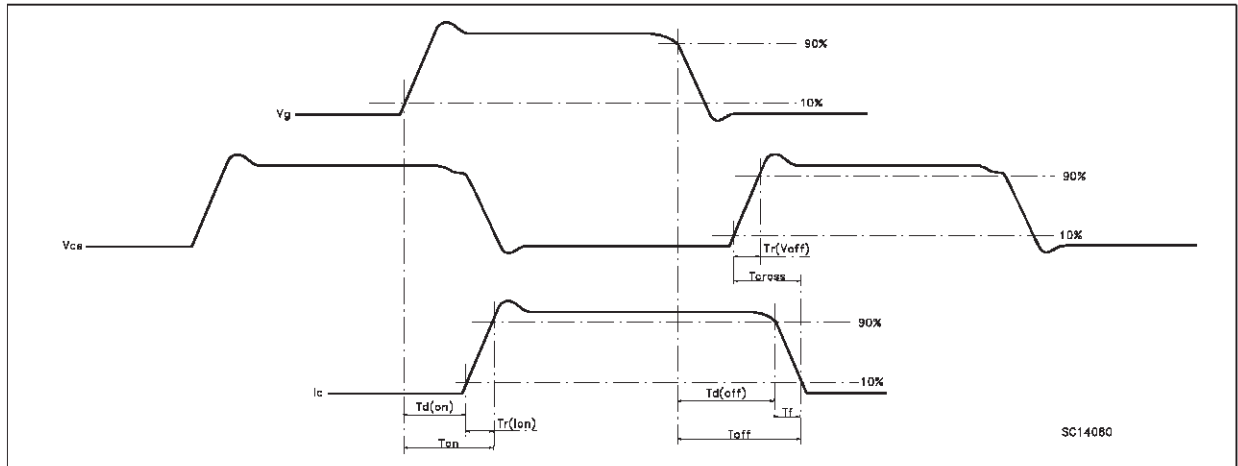
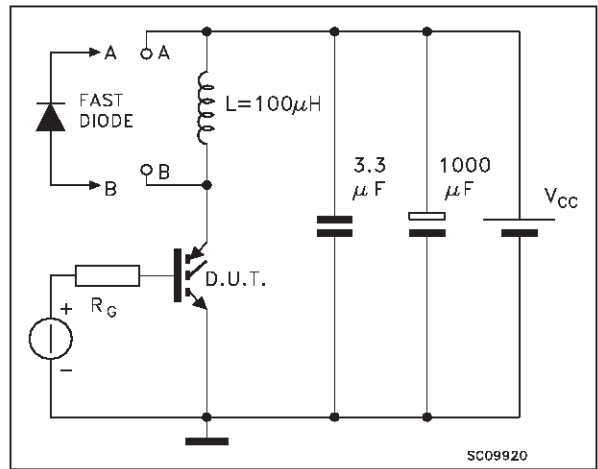
Turn-Off SOA



**Fig. 1: Gate Charge test Circuit**

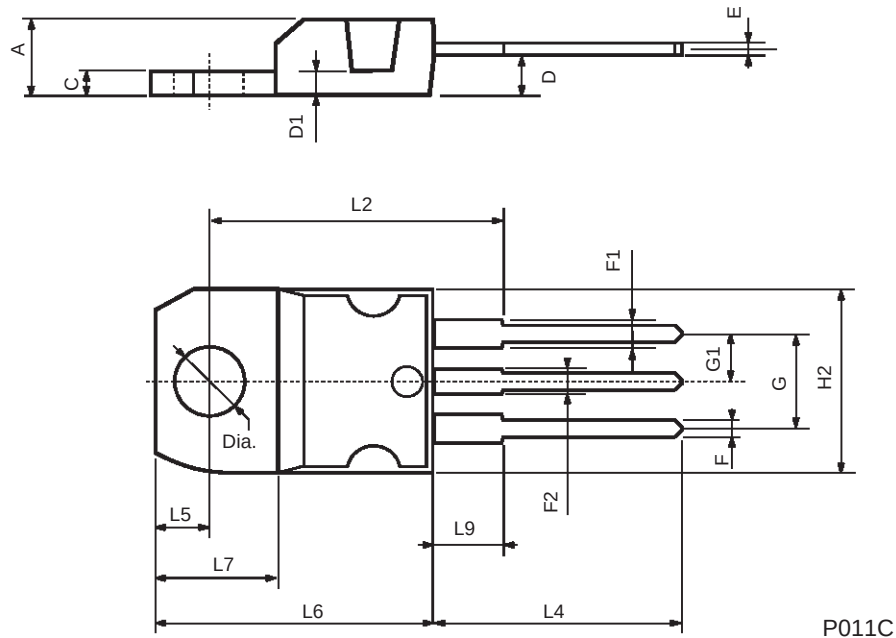


**Fig. 2: Test Circuit For Inductive Load Switching**



TO-220 MECHANICAL DATA

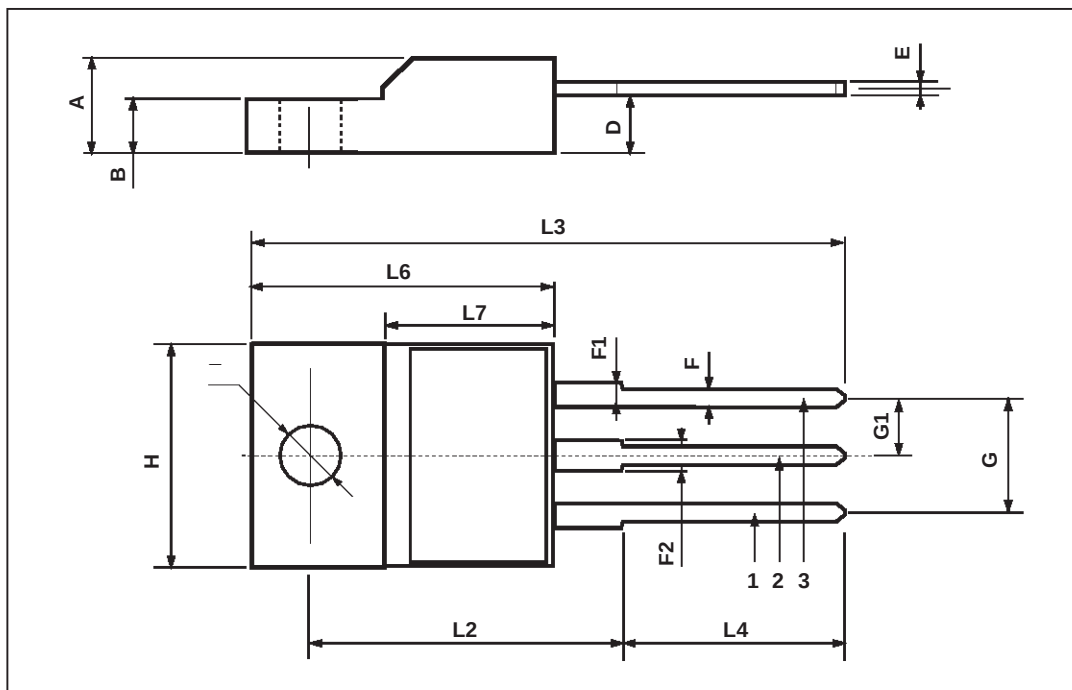
| DIM. | mm    |      |       | inch  |       |       |
|------|-------|------|-------|-------|-------|-------|
|      | MIN.  | TYP. | MAX.  | MIN.  | TYP.  | MAX.  |
| A    | 4.40  |      | 4.60  | 0.173 |       | 0.181 |
| C    | 1.23  |      | 1.32  | 0.048 |       | 0.051 |
| D    | 2.40  |      | 2.72  | 0.094 |       | 0.107 |
| D1   |       | 1.27 |       |       | 0.050 |       |
| E    | 0.49  |      | 0.70  | 0.019 |       | 0.027 |
| F    | 0.61  |      | 0.88  | 0.024 |       | 0.034 |
| F1   | 1.14  |      | 1.70  | 0.044 |       | 0.067 |
| F2   | 1.14  |      | 1.70  | 0.044 |       | 0.067 |
| G    | 4.95  |      | 5.15  | 0.194 |       | 0.203 |
| G1   | 2.4   |      | 2.7   | 0.094 |       | 0.106 |
| H2   | 10.0  |      | 10.40 | 0.393 |       | 0.409 |
| L2   |       | 16.4 |       |       | 0.645 |       |
| L4   | 13.0  |      | 14.0  | 0.511 |       | 0.551 |
| L5   | 2.65  |      | 2.95  | 0.104 |       | 0.116 |
| L6   | 15.25 |      | 15.75 | 0.600 |       | 0.620 |
| L7   | 6.2   |      | 6.6   | 0.244 |       | 0.260 |
| L9   | 3.5   |      | 3.93  | 0.137 |       | 0.154 |
| DIA. | 3.75  |      | 3.85  | 0.147 |       | 0.151 |





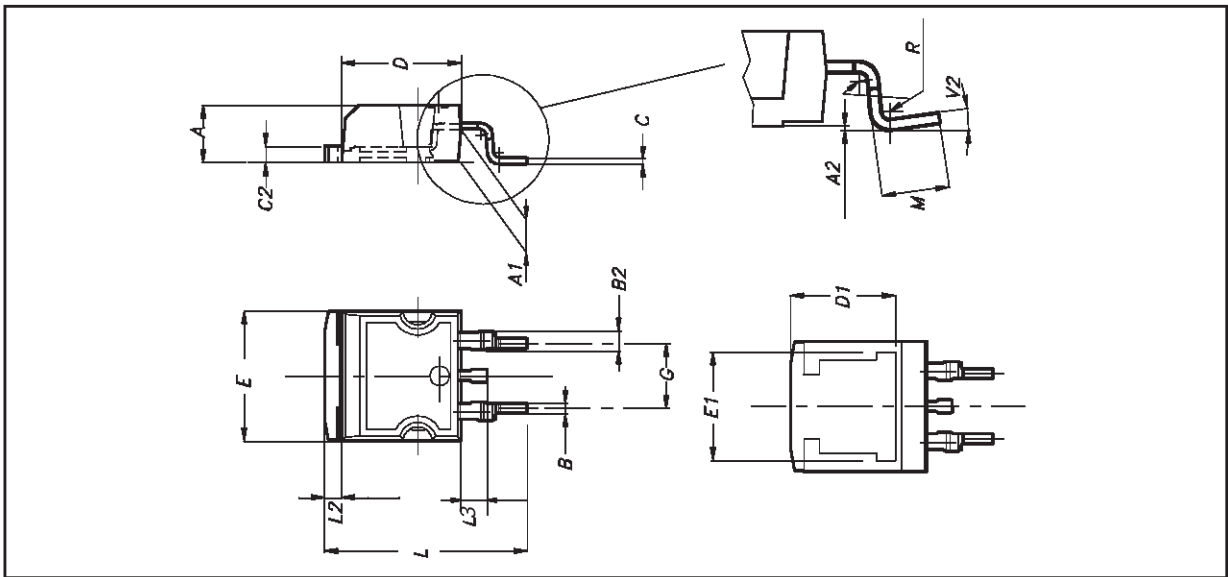
## TO-220FP MECHANICAL DATA

| DIM. | mm   |      |      | inch  |       |       |
|------|------|------|------|-------|-------|-------|
|      | MIN. | TYP. | MAX. | MIN.  | TYP.  | MAX.  |
| A    | 4.4  |      | 4.6  | 0.173 |       | 0.181 |
| B    | 2.5  |      | 2.7  | 0.098 |       | 0.106 |
| D    | 2.5  |      | 2.75 | 0.098 |       | 0.108 |
| E    | 0.45 |      | 0.7  | 0.017 |       | 0.027 |
| F    | 0.75 |      | 1    | 0.030 |       | 0.039 |
| F1   | 1.15 |      | 1.7  | 0.045 |       | 0.067 |
| F2   | 1.15 |      | 1.7  | 0.045 |       | 0.067 |
| G    | 4.95 |      | 5.2  | 0.195 |       | 0.204 |
| G1   | 2.4  |      | 2.7  | 0.094 |       | 0.106 |
| H    | 10   |      | 10.4 | 0.393 |       | 0.409 |
| L2   |      | 16   |      |       | 0.630 |       |
| L3   | 28.6 |      | 30.6 | 1.126 |       | 1.204 |
| L4   | 9.8  |      | 10.6 | 0.385 |       | 0.417 |
| L6   | 15.9 |      | 16.4 | 0.626 |       | 0.645 |
| L7   | 9    |      | 9.3  | 0.354 |       | 0.366 |
| Ø    | 3    |      | 3.2  | 0.118 |       | 0.126 |



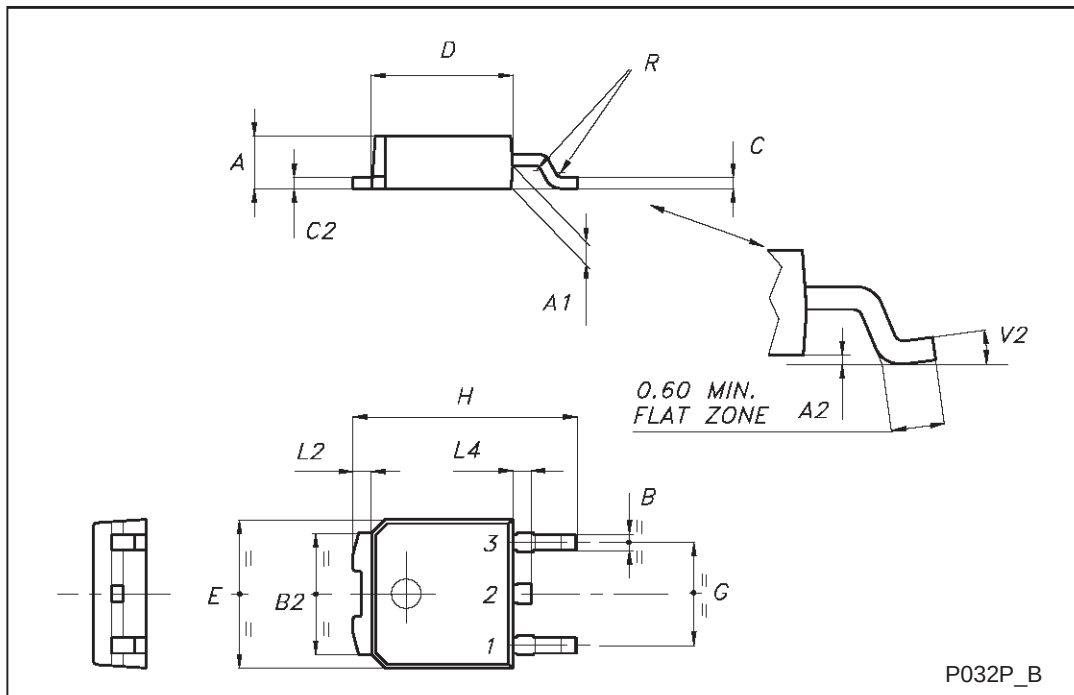
D<sup>2</sup>PAK MECHANICAL DATA

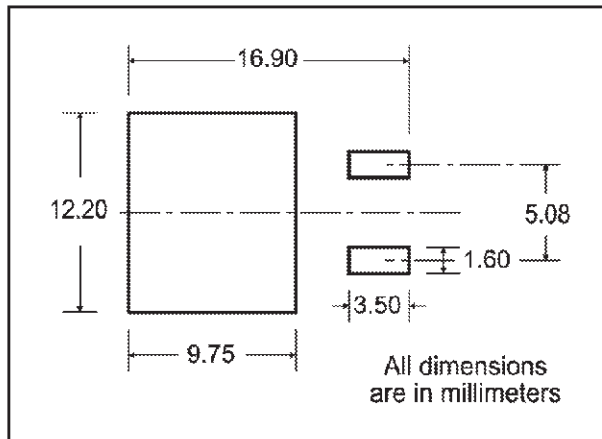
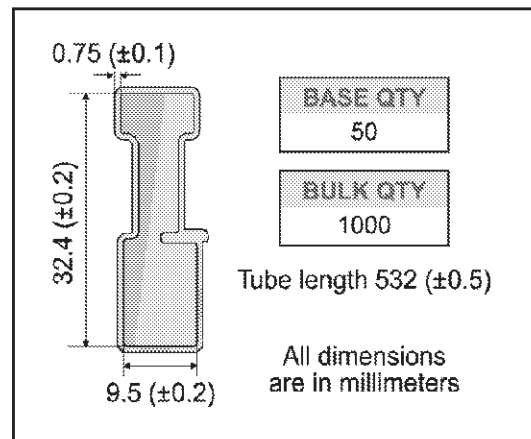
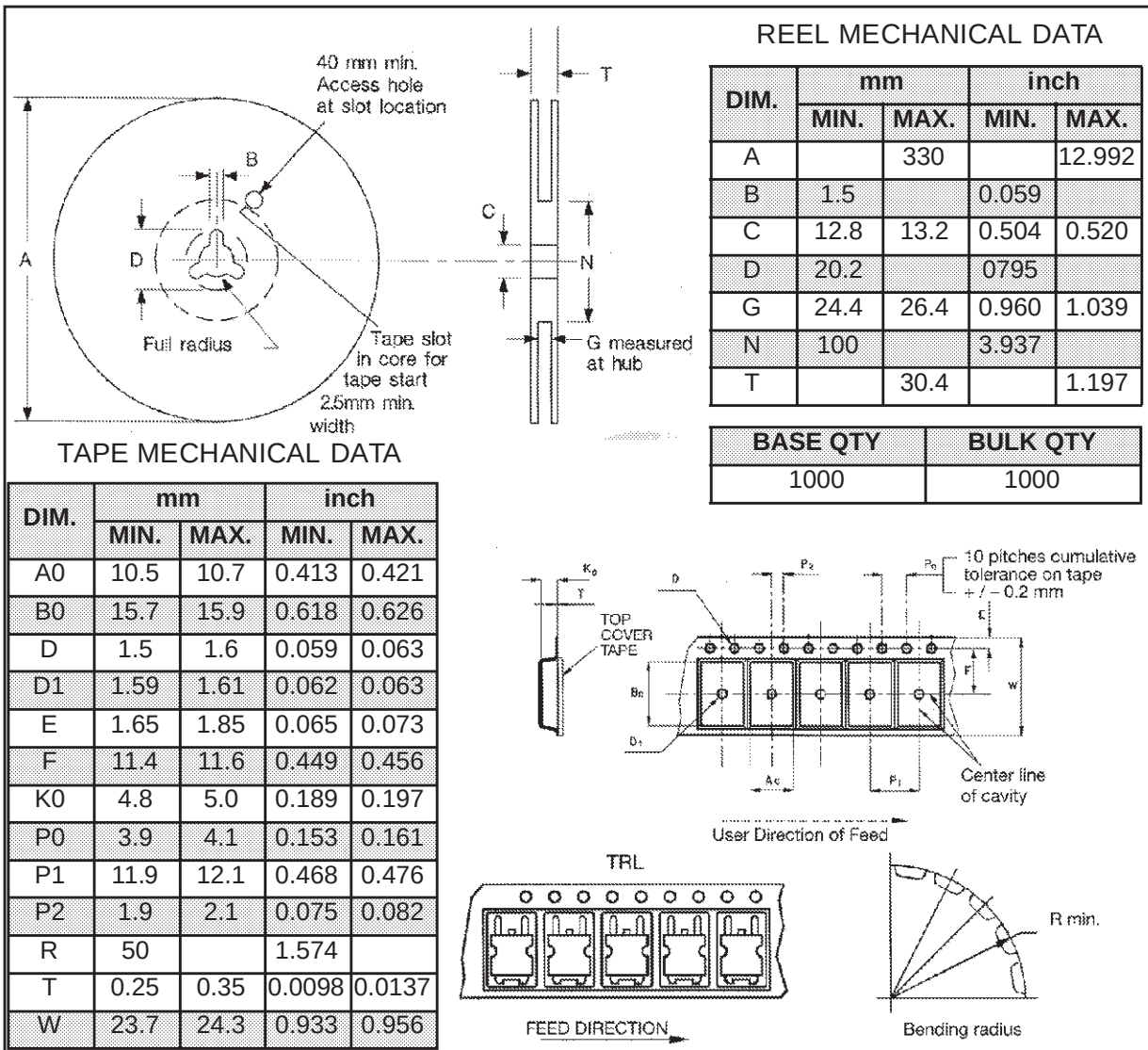
| DIM. | mm.  |     |       | inch  |       |       |
|------|------|-----|-------|-------|-------|-------|
|      | MIN. | TYP | MAX.  | MIN.  | TYP.  | MAX.  |
| A    | 4.4  |     | 4.6   | 0.173 |       | 0.181 |
| A1   | 2.49 |     | 2.69  | 0.098 |       | 0.106 |
| A2   | 0.03 |     | 0.23  | 0.001 |       | 0.009 |
| B    | 0.7  |     | 0.93  | 0.027 |       | 0.036 |
| B2   | 1.14 |     | 1.7   | 0.044 |       | 0.067 |
| C    | 0.45 |     | 0.6   | 0.017 |       | 0.023 |
| C2   | 1.23 |     | 1.36  | 0.048 |       | 0.053 |
| D    | 8.95 |     | 9.35  | 0.352 |       | 0.368 |
| D1   |      | 8   |       |       | 0.315 |       |
| E    | 10   |     | 10.4  | 0.393 |       |       |
| E1   |      | 8.5 |       |       | 0.334 |       |
| G    | 4.88 |     | 5.28  | 0.192 |       | 0.208 |
| L    | 15   |     | 15.85 | 0.590 |       | 0.625 |
| L2   | 1.27 |     | 1.4   | 0.050 |       | 0.055 |
| L3   | 1.4  |     | 1.75  | 0.055 |       | 0.068 |
| M    | 2.4  |     | 3.2   | 0.094 |       | 0.126 |
| R    |      | 0.4 |       |       | 0.015 |       |
| V2   | 0°   |     | 8°    |       |       |       |



## TO-252 (DPAK) MECHANICAL DATA

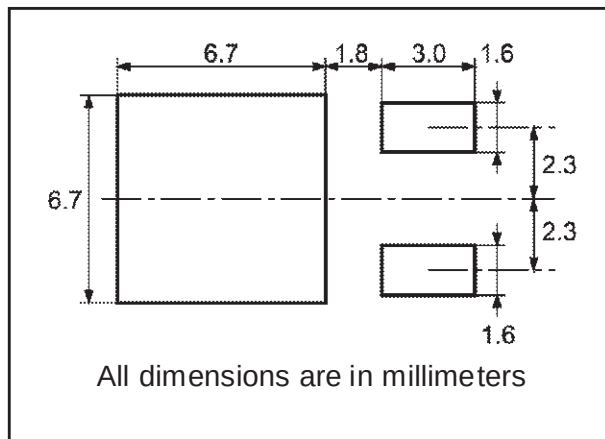
| DIM. | mm   |      |       | inch  |       |       |
|------|------|------|-------|-------|-------|-------|
|      | MIN. | TYP. | MAX.  | MIN.  | TYP.  | MAX.  |
| A    | 2.20 |      | 2.40  | 0.087 |       | 0.094 |
| A1   | 0.90 |      | 1.10  | 0.035 |       | 0.043 |
| A2   | 0.03 |      | 0.23  | 0.001 |       | 0.009 |
| B    | 0.64 |      | 0.90  | 0.025 |       | 0.035 |
| B2   | 5.20 |      | 5.40  | 0.204 |       | 0.213 |
| C    | 0.45 |      | 0.60  | 0.018 |       | 0.024 |
| C2   | 0.48 |      | 0.60  | 0.019 |       | 0.024 |
| D    | 6.00 |      | 6.20  | 0.236 |       | 0.244 |
| E    | 6.40 |      | 6.60  | 0.252 |       | 0.260 |
| G    | 4.40 |      | 4.60  | 0.173 |       | 0.181 |
| H    | 9.35 |      | 10.10 | 0.368 |       | 0.398 |
| L2   |      | 0.8  |       |       | 0.031 |       |
| L4   | 0.60 |      | 1.00  | 0.024 |       | 0.039 |
| V2   | 0°   |      | 8°    | 0°    |       | 0°    |



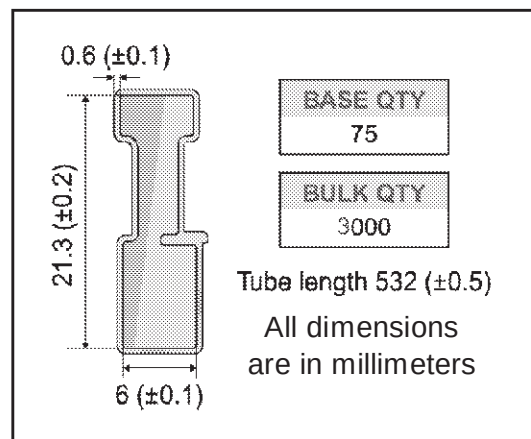
**D<sup>2</sup>PAK FOOTPRINT****TUBE SHIPMENT (no suffix)\*****TAPE AND REEL SHIPMENT (suffix "T4")\***

\* on sales type

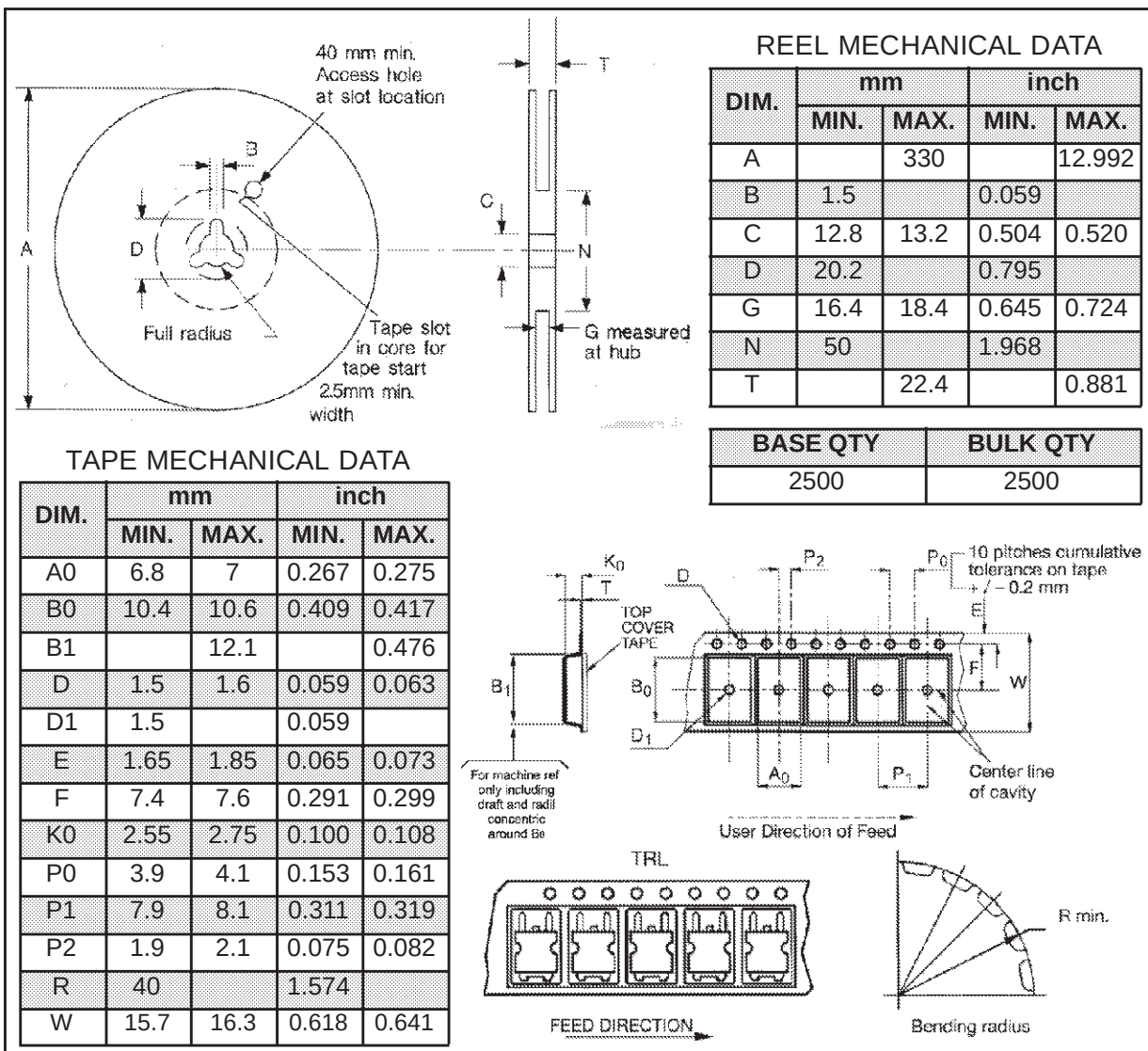
## DPAK FOOTPRINT



## TUBE SHIPMENT (no suffix)\*



## TAPE AND REEL SHIPMENT (suffix "T4")\*



\* on sales

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

© The ST logo is a registered trademark of STMicroelectronics

© 2002 STMicroelectronics - Printed in Italy - All Rights Reserved  
STMicroelectronics GROUP OF COMPANIES

Australia - Brazil - Canada - China - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco  
Singapore - Spain - Sweden - Switzerland - United Kingdom - United States.

© <http://www.st.com>